



DMJ70H900HJ3

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	Ι _D T _C = +25°C
700V	$0.9\Omega @ V_{GS} = 10V$	7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

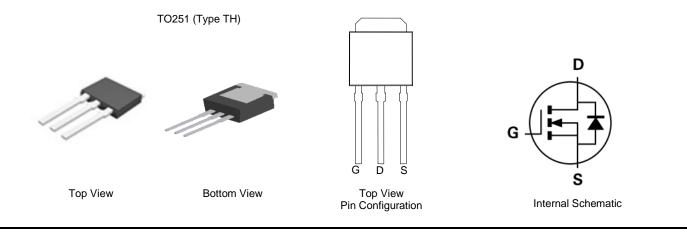
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

Features and Benefits

- Low On-Resistance
- High BV_{DSS} Rating for Power Application
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO251(Type TH)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.33 grams (Approximate)



Ordering Information (Note 4)

Part Number		Case	Packaging			
DMJ70H900HJ3		TO251 (Type TH)	75 Pieces / Tube			
Notes:	otes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

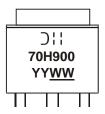
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

TO251 (Type TH)



D ! ! = Manufacturer's Marking 70H900 = Product Type Marking Code YY<u>WW</u> = Date Code Marking YY or <u>YY</u>= Last Two Digits of Year (ex: 16 = 2016) WW or <u>WW</u> = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	700	V	
Gate-Source Voltage	V _{GSS}	±30	V	
Continuous Drain Current (Note 5) V_{GS} = 10V	T _C = +25°C T _C = +100°C	Ι _D	7 4	А
Maximum Body Diode Forward Current (Note 6)	·	ls	1.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	10	А
Avalanche Current (Note 7)	L = 60mH	I _{AS}	1.3	А
Avalanche Energy (Note 7)	L = 60mH	E _{AS}	50	mJ
Peak Diode Recovery dv/dt (Note 7)		dv/dt	8	V/ns

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_C = +25^{\circ}C$	D	68	W	
Total Power Dissipation (Note 5)	$T_{\rm C} = +100^{\circ}{\rm C}$	PD	27	vv	
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	79	°C/W		
Thermal Resistance, Junction to Case (Note 5)	R _{θJC}	1.8	-C/VV		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	700	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	V _{DS} = 700V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	2	3.4	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	0.7	0.9	Ω	$V_{GS} = 10V, I_D = 1.5A$	
Diode Forward Voltage	V _{SD}	_	0.85	1.3	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C _{iss}	_	603	_		V _{DS} = 50V, f = 1MHz, V _{GS} = 0V	
Output Capacitance	C _{oss}	_	230		pF		
Reverse Transfer Capacitance	C _{rss}	_	16				
Gate Resistance	Rg	_	4		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	18.4				
Gate-Source Charge	Q _{gs}		2.1		nC	$V_{DD} = 560V, I_D = 5A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}	_	9.8			VGS = 10V	
Turn-On Delay Time	t _{D(ON)}	_	8.7	_			
Turn-On Rise Time	t _R	_	18.7			$\label{eq:VDD} \begin{split} V_{DD} &= 350 V, \ V_{GS} = 10 V, \\ R_g &= 4.7 \Omega, \ I_D = 5 A \end{split}$	
Turn-Off Delay Time	t _{D(OFF)}	_	28.5	—	ns		
Turn-Off Fall Time	t _F	_	10.7		1		
Body Diode Reverse Recovery Time	t _{RR}	_	239		ns		
Body Diode Reverse Recovery Charge	Q _{RR}		2.2		μC	— I _S = 5A, di/dt = 100A/μs	

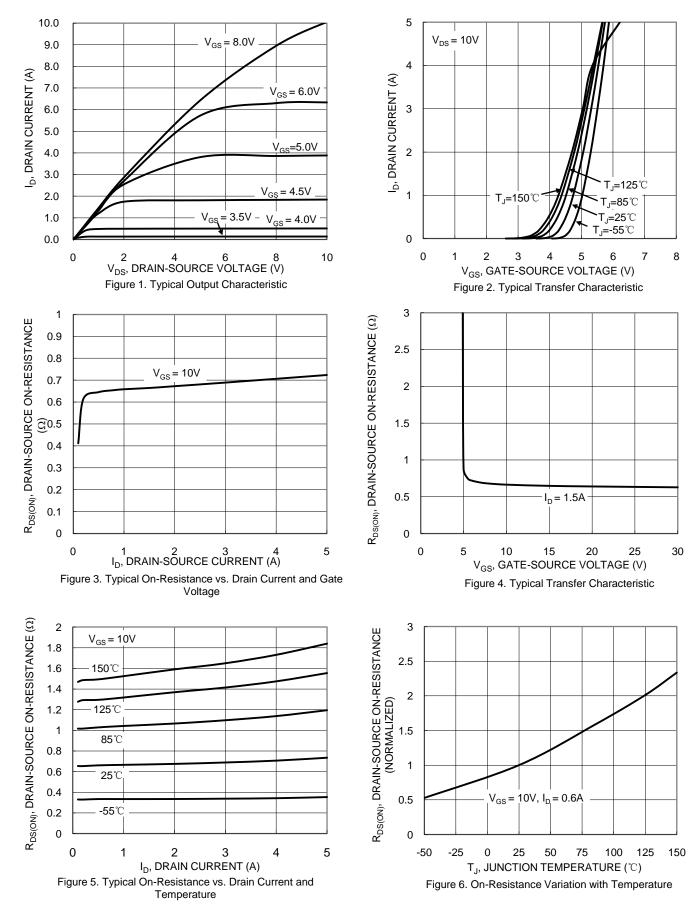
Notes: 5. Device mounted on infinite heatsink.

6. Device mounted on FR-4 substrate PC board, 2oz. copper, with minimum recommended pad layout.

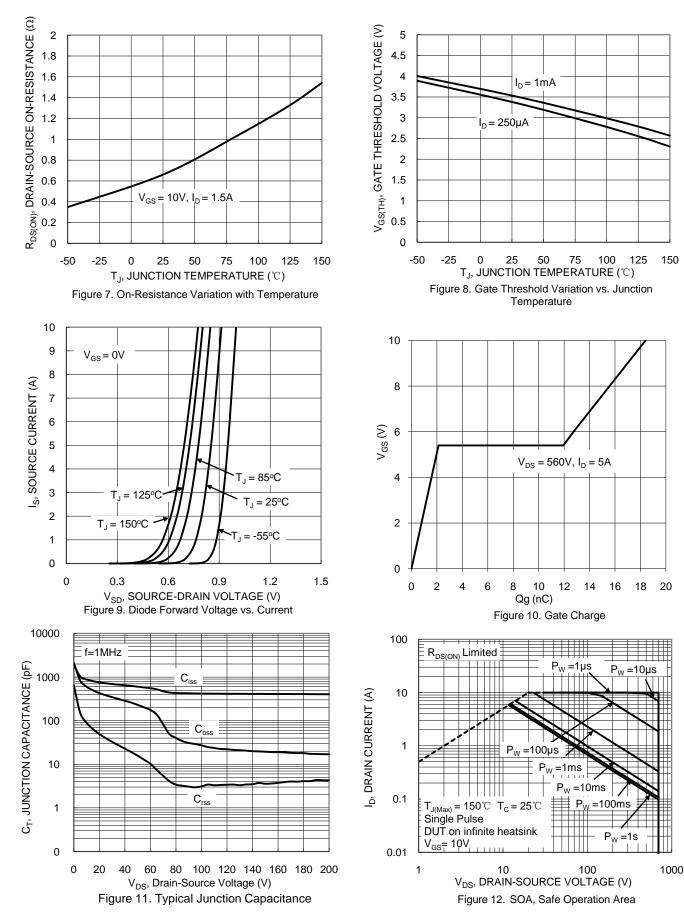
Guaranteed by design. Not subject to production testing.
Short duration pulse test used to minimize self-heating effect.



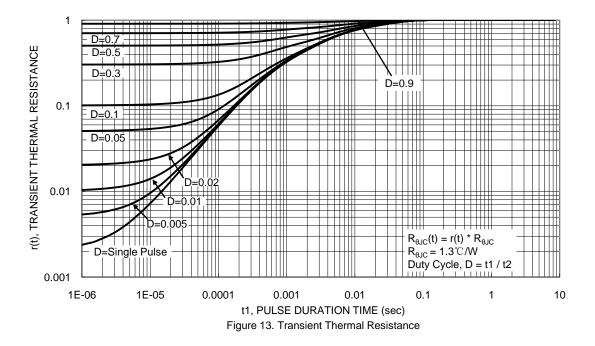
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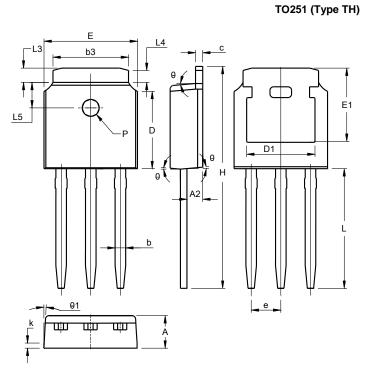






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



	TO251 (Type TH)					
Dim	Min	Max	Тур			
Α	2.20	2.40	2.30			
A2	0.97	1.17	1.07			
b	0.68	0.90	0.78			
b3	5.20	5.50	5.33			
С	0.43	0.63	0.53			
D	5.98	6.22	6.10			
D1	47	5.30 REF	=			
е	2	.286 BS	С			
E	6.40	6.80	6.60			
E1	4.63	5.03	4.83			
н	16.22	16.82	16.52			
k	Ū	0.40REF	-			
L	9.15	9.65	9.40			
L3	0.88	1.28	1.02			
L4	0.75 REF					
L5	1.65	1.95	1.80			
PØ	1.20					
θ	5°	9°	7°			
θ1	5°	9°	7°			
All Dimensions in mm						



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